

μ A78M00 SERIES POSITIVE-VOLTAGE REGULATORS

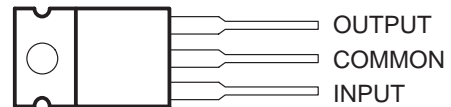
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- 3-Terminal Regulators
- Output Current up to 500 mA
- No External Components
- Internal Thermal-Overload Protection
- High Power-Dissipation Capability
- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Direct Replacements for Fairchild μ A78M00 Series

description

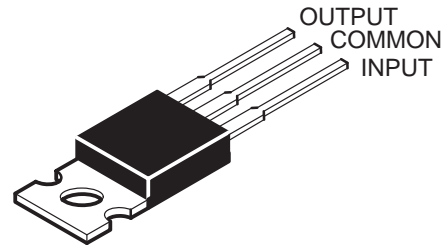
This series of fixed-voltage monolithic integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 500 mA of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power-pass element in precision regulators.

KC PACKAGE
(TOP VIEW)

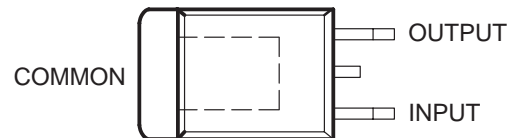


The common terminal is in electrical contact with the mounting base.

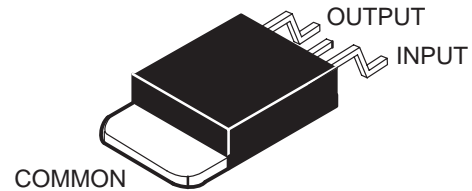
TO-220AB



KTP PACKAGE
(TOP VIEW)



The common terminal is in electrical contact with the mounting base.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS
INSTRUMENTS**

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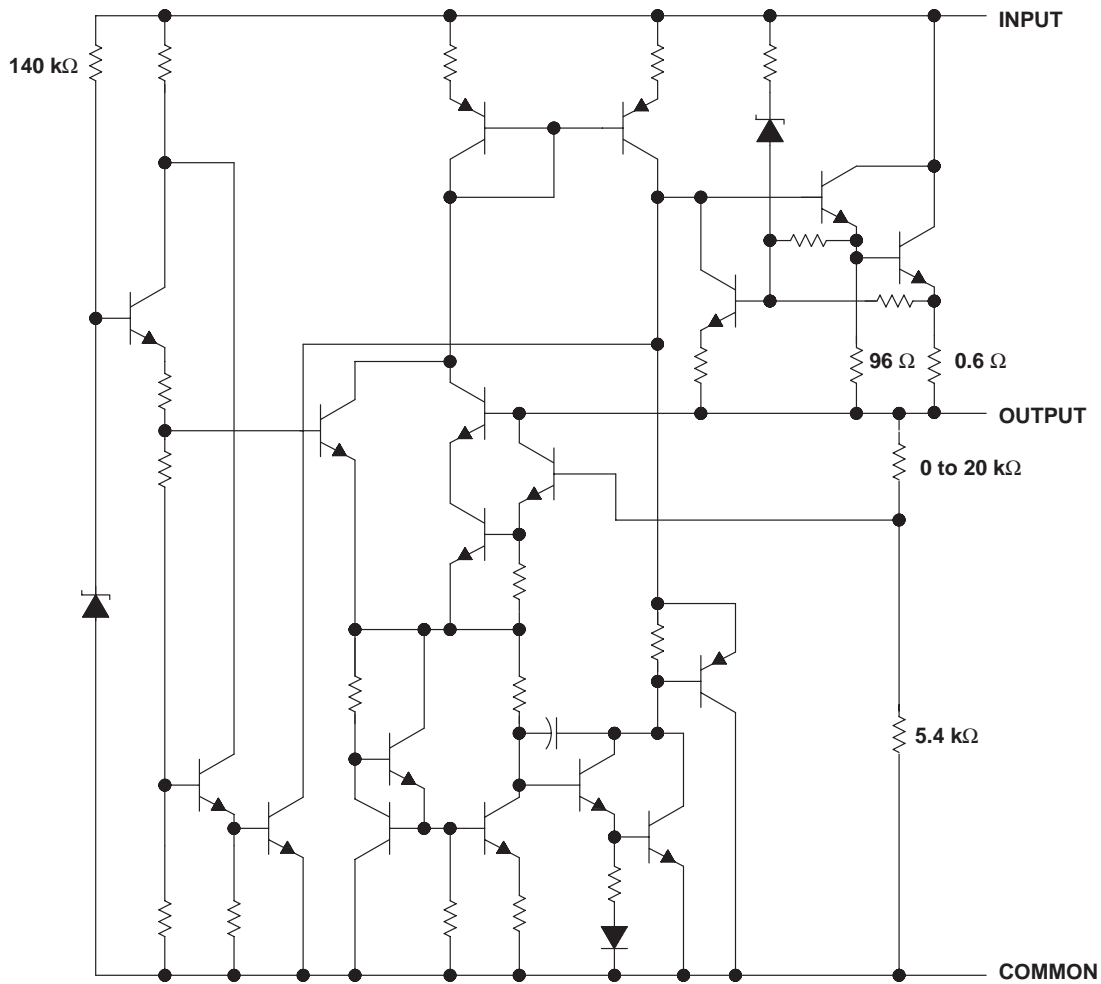
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AVAILABLE OPTIONS

T _J	V _{O(NOM)} (V)	PACKAGED DEVICES		CHIP FORM (Y)
		HEAT-SINK MOUNTED (KC)	PLASTIC FLANGE MOUNTED† (KTP)	
0°C to 125°C	5	μA78M05CKC	μA78M05CKTP	μA78M05Y
	6	μA78M06CKC	μA78M06CKTP	μA78M06Y
	8	μA78M08CKC	μA78M08CKTP	μA78M08Y
	9	μA78M09CKC	μA78M09CKTP	μA78M09Y
	10	μA78M10CKC	μA78M10CKTP	μA78M10Y
	12	μA78M12CKC	μA78M12CKTP	μA78M12Y
	15	μA78M15CKC	μA78M15CKTP	μA78M15Y
	20	μA78M20CKC	μA78M20CKTP	μA78M20Y
	24	μA78M24CKC	μA78M24CKTP	μA78M24Y

† The KTP package is only available taped and reeled (e.g., μA78M05CKTPR).

schematic



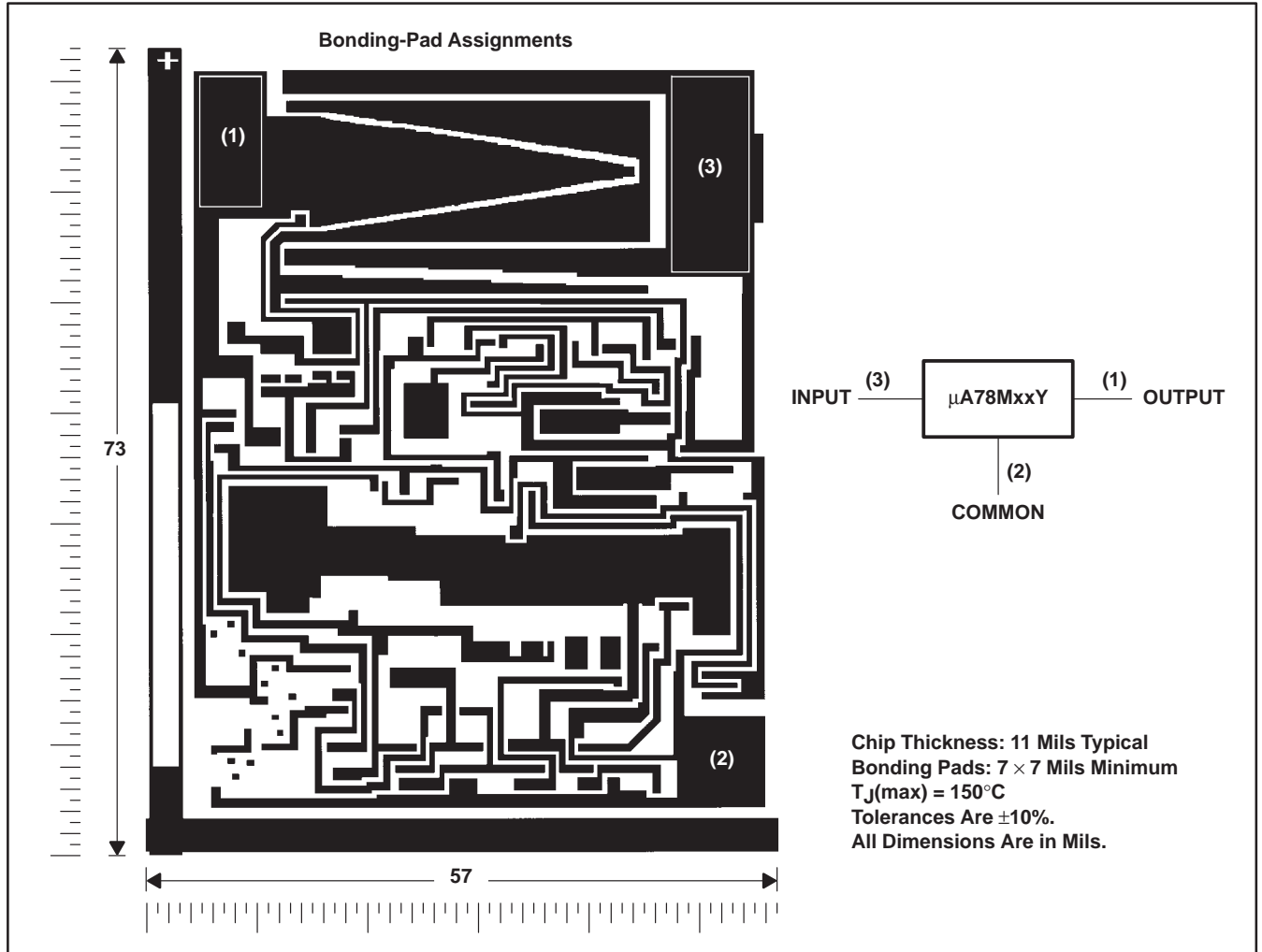
Resistor values shown are nominal.



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μA78MxxY chip information

This chip, when properly assembled, has characteristics similar to the μA78MxxC. Thermal compression or ultrasonic bonding can be used on the doped-aluminum bonding pads. The chip can be mounted with conductive epoxy or a gold-silicon preform.



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absolute maximum ratings over operating temperature range (unless otherwise noted)†

		μA78Mxx	UNIT
Input voltage, V_I	μA78M20, μA78M24	40	V
	All others	35	
Continuous total power dissipation (see Note 1)		See Dissipation Rating Tables	
Virtual junction temperature range, T_J		0 to 150	°C
Storage temperature range, T_{stg}		-65 to 150	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		260	°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: To avoid exceeding the design maximum virtual junction temperature, these ratings should not be exceeded. Due to variations in individual device electrical characteristics and thermal resistance, the built-in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.

DISSIPATION RATING – FREE-AIR TEMPERATURE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING
KC	2000 mW	16.0 mW/°C	1280 mW
KTP	1800 mW	14.5 mW/°C	1147 mW

DISSIPATION RATING – CASE TEMPERATURE

PACKAGE	$T_C \leq 50^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_C = 50^\circ\text{C}$	$T_C = 125^\circ\text{C}$ POWER RATING
KC	20000 mW	200.0 mW/°C	5000 mW
KTP	18000 mW	181.8 mW/°C	4365 mW

recommended operating conditions

		MIN	MAX	UNIT
Input voltage, V_I	μA78M05	7	25	V
	μA78M06	8	25	
	μA78M08	10.5	25	
	μA78M09	11.5	26	
	μA78M10	12.5	28	
	μA78M12	14.5	30	
	μA78M15	17.5	30	
	μA78M20	23	35	
	μA78M24	27	38	
Output current, I_O		500		mA
Operating virtual junction temperature, T_J		0	125	°C



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electrical characteristics at specified virtual junction temperature, $V_I = 10\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITION [†]		μA78M05C			UNIT
			MIN	TYP	MAX	
Output voltage [‡]			4.8	5	5.2	V
	$V_I = 7\text{ V to }20\text{ V}$,	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	4.75		5.25	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 7\text{ V to }25\text{ V}$		3	100	mV
		$V_I = 8\text{ V to }20\text{ V}$				
		$V_I = 8\text{ V to }25\text{ V}$		1	50	
Ripple rejection	$V_I = 8\text{ V to }18\text{ V}$,	$f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		62	dB
			$I_O = 300\text{ mA}$		62	
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			20	100	mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10	50	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$,	$T_J = 0^\circ\text{C to }125^\circ\text{C}$		-1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			40	200	μV
Dropout voltage				2		V
Bias current				4.5	6	mA
Bias current change	$I_O = 200\text{ mA}$,		$V_I = 8\text{ V to }25\text{ V}$,		$T_J = 0^\circ\text{C to }125^\circ\text{C}$	
	$I_O = 5\text{ mA to }350\text{ mA}$,		$T_J = 0^\circ\text{C to }125^\circ\text{C}$		0.8	mA
Short-circuit output current	$V_I = 35\text{ V}$			300		mA
Peak output current				0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

[‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

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electrical characteristics at specified virtual junction temperature, $V_I = 11\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	μA78M06C			UNIT	
		MIN	TYP	MAX		
Output voltage‡		5.75	6	6.25	V	
	$I_O = 5\text{ mA to }350\text{ mA}$, $V_I = 8\text{ V to }21\text{ V}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	5.7		6.3		
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 8\text{ V to }25\text{ V}$		5	100	mV
		$V_I = 9\text{ V to }25\text{ V}$		1.5	50	
Ripple rejection	$V_I = 9\text{ V to }19\text{ V}$, $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		59		dB
		$I_O = 300\text{ mA}$		59	80	
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		20	120	mV	
	$I_O = 5\text{ mA to }200\text{ mA}$		10	60		
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		-1		mV/°C	
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		45		μV	
Dropout voltage			2		V	
Bias current			4.5	6	mA	
Bias current change	$V_I = 9\text{ V to }25\text{ V}$, $I_O = 200\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		0.8		mA	
	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		0.5			
Short-circuit output current	$V_I = 35\text{ V}$		270		mA	
Peak output current			0.7		A	

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

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electrical characteristics at specified virtual junction temperature, $V_I = 14\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		μA78M08C			UNIT
			MIN	TYP	MAX	
Output voltage‡			7.7	8	8.3	V
	$V_I = 10.5\text{ V to }23\text{ V}$,	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	7.6		8.4	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 10.5\text{ V to }25\text{ V}$		6	100	mV
		$V_I = 11\text{ V to }25\text{ V}$		2	50	
Ripple rejection	$V_I = 11.5\text{ V to }21.5\text{ V}$, $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	56			dB
			$I_O = 300\text{ mA}$	56		
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		25	160		mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10	80		
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$,	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	-1			mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		52			μV
Dropout voltage			2			V
Bias current			4.6	6		mA
Bias current change	$V_I = 10.5\text{ V to }25\text{ V}$, $I_O = 200\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.5	
Short-circuit output current	$V_I = 35\text{ V}$	$V_I = 35\text{ V}$	250			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

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electrical characteristics at specified virtual junction temperature, $V_I = 16\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	μA78M09C			UNIT	
		MIN	TYP	MAX		
Output voltage‡		8.6	9	9.4	V	
	$V_I = 11.5\text{ V to }24\text{ V}$, $I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	8.5		9.5		
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 11.5\text{ V to }26\text{ V}$		6	100	mV
		$V_I = 12\text{ V to }26\text{ V}$		2	50	
Ripple rejection	$V_I = 13\text{ V to }23\text{ V}$, $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		56		dB
		$I_O = 300\text{ mA}$		56	80	
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		25	180	mV	
	$I_O = 5\text{ mA to }200\text{ mA}$		10	90		
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		-1		mV/°C	
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		58		μV	
Dropout voltage			2		V	
Bias current			4.6	6	mA	
Bias current change	$V_I = 11.5\text{ V to }26\text{ V}$, $I_O = 200\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		0.8		mA	
	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		0.5			
Short-circuit output current	$V_I = 35\text{ V}$		250		mA	
Peak output current			0.7		A	

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

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electrical characteristics at specified virtual junction temperature, $V_I = 17\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		μA78M10C			UNIT
			MIN	TYP	MAX	
Output voltage‡			9.6	10	10.4	V
	$V_I = 12.5\text{ V to }25\text{ V}$,	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	9.5		10.5	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 12.5\text{ V to }28\text{ V}$		7	100	mV
		$V_I = 14\text{ V to }28\text{ V}$		2	50	
Ripple rejection	$V_I = 15\text{ V to }25\text{ V}$,	$f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	59		dB
				$I_O = 300\text{ mA}$	55	
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		25	200		mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10	100		
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$,	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	-1			mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		64			μV
Dropout voltage			2			V
Bias current			4.7	6		mA
Bias current change	$V_I = 12.5\text{ V to }28\text{ V}$, $I_O = 200\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		0.8			mA
	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		0.5			
Short-circuit output current	$V_I = 35\text{ V}$		245			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

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electrical characteristics at specified virtual junction temperature, $V_I = 19\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	μA78M12C			UNIT
		MIN	TYP	MAX	
Output voltage‡		11.5	12	12.5	V
	$V_I = 14.5\text{ V to }27\text{ V}$, $I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	11.4		12.6	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 14.5\text{ V to }30\text{ V}$			mV
		$V_I = 16\text{ V to }30\text{ V}$			
Ripple rejection	$V_I = 15\text{ V to }25\text{ V}$, $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$			dB
		$I_O = 300\text{ mA}$			
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$	25 240			mV
	$I_O = 5\text{ mA to }200\text{ mA}$	10 120			
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$	-1			mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$	75			μV
Dropout voltage		2			V
Bias current		4.8 6			mA
Bias current change	$V_I = 14.5\text{ V to }30\text{ V}$, $I_O = 200\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$			0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$			0.5	
Short-circuit output current	$V_I = 35\text{ V}$	240			mA
Peak output current		0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

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electrical characteristics at specified virtual junction temperature, $V_I = 23\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITION [†]		μA78M15C			UNIT
			MIN	TYP	MAX	
Output voltage [‡]			14.4	15	15.6	V
	$V_I = 17.5\text{ V to }30\text{ V}$,	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	14.25		15.75	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 17.5\text{ V to }30\text{ V}$		10	100	mV
		$V_I = 20\text{ V to }30\text{ V}$		3	50	
Ripple rejection	$V_I = 18.5\text{ V to }28.5\text{ V}$, $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	54			dB
		$I_O = 300\text{ mA}$	54	70		
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			25	300	mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10	150	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$,	$T_J = 0^\circ\text{C to }125^\circ\text{C}$		-1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$			90		μV
Dropout voltage				2		V
Bias current				4.8	6	mA
Bias current change	$V_I = 17.5\text{ V to }30\text{ V}$, $I_O = 200\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.5	
Short-circuit output current	$V_I = 35\text{ V}$			240		mA
Peak output current				0.7		A

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

[‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

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electrical characteristics at specified virtual junction temperature, $V_I = 29\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	μA78M20C			UNIT	
		MIN	TYP	MAX		
Output voltage‡		19.2	20	20.8	V	
	$V_I = 23\text{ V to }35\text{ V}$, $I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	19		21		
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 23\text{ V to }35\text{ V}$		10	100	mV
		$V_I = 24\text{ V to }35\text{ V}$		5	50	
Ripple rejection	$V_I = 24\text{ V to }34\text{ V}$, $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		53		dB
		$I_O = 300\text{ mA}$		53	70	
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		30	400	mV	
	$I_O = 5\text{ mA to }200\text{ mA}$		10	200		
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		-1.1		mV/°C	
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		110		μV	
Dropout voltage			2		V	
Bias current			4.9	6	mA	
Bias current change	$V_I = 23\text{ V to }35\text{ V}$, $I_O = 200\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		0.8		mA	
	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$		0.5			
Short-circuit output current	$V_I = 35\text{ V}$		240		mA	
Peak output current			0.7		A	

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



electrical characteristics at specified virtual junction temperature, $V_I = 33\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		μA78M24C			UNIT
			MIN	TYP	MAX	
Output voltage‡			23	24	25	V
	$V_I = 27\text{ V to }38\text{ V}$,	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	22.8		25.2	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 27\text{ V to }38\text{ V}$		10	100	mV
		$V_I = 28\text{ V to }38\text{ V}$		5	50	
Ripple rejection	$V_I = 28\text{ V to }38\text{ V}$, $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	50			dB
			$I_O = 300\text{ mA}$	50	70	
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$			30	480	mV
	$I_O = 5\text{ mA to }200\text{ mA}$			10	240	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$,	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	-1.2			mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		170			μV
Dropout voltage			2			V
Bias current			5	6		mA
Bias current change	$V_I = 27\text{ V to }38\text{ V}$, $I_O = 200\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$				0.5	
Short-circuit output current	$V_I = 35\text{ V}$		240			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 10\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		μA78M05Y			UNIT
			MIN	TYP	MAX	
Output voltage‡			5			V
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 7\text{ V to }25\text{ V}$	3			mV
		$V_I = 8\text{ V to }25\text{ V}$	1			
Ripple rejection	$V_I = 8\text{ V to }18\text{ V}$,	$I_O = 300\text{ mA}$, $f = 120\text{ Hz}$	80			dB
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		20			mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10			
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$		-1			mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		40			μV
Dropout voltage			2			V
Bias current			4.5			mA
Short-circuit output current	$V_I = 35\text{ V}$		300			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.

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electrical characteristics at specified virtual junction temperature, $V_I = 11\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	μA78M06Y			UNIT
		MIN	TYP	MAX	
Output voltage‡			6		V
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 8\text{ V to }25\text{ V}$	5		mV
		$V_I = 9\text{ V to }25\text{ V}$	1.5		
Ripple rejection	$V_I = 9\text{ V to }19\text{ V}$, $I_O = 300\text{ mA}$, $f = 120\text{ Hz}$		80		dB
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		20		mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10		
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$		-1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		45		μV
Dropout voltage			2		V
Bias current			4.5		mA
Short-circuit output current	$V_I = 35\text{ V}$		270		mA
Peak output current			0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 14\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	μA78M08Y			UNIT
		MIN	TYP	MAX	
Output voltage‡			8		V
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 10.5\text{ V to }25\text{ V}$	6		mV
		$V_I = 11\text{ V to }25\text{ V}$	2		
Ripple rejection	$V_I = 11.5\text{ V to }21.5\text{ V}$, $I_O = 300\text{ mA}$, $f = 120\text{ Hz}$		80		dB
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		25		mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10		
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$		-1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		52		μV
Dropout voltage			2		V
Bias current			4.6		mA
Short-circuit output current	$V_I = 35\text{ V}$		250		mA
Peak output current			0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



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electrical characteristics at specified virtual junction temperature, $V_I = 16\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		μA78M09Y			UNIT
			MIN	TYP	MAX	
Output voltage‡			9			V
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 11.5\text{ V to }26\text{ V}$	6			mV
		$V_I = 12\text{ V to }26\text{ V}$	2			
Ripple rejection	$V_I = 13\text{ V to }23\text{ V}$,	$I_O = 300\text{ mA}$, $f = 120\text{ Hz}$	80			dB
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		25			mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10			
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$,	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	-1			mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		58			μV
Dropout voltage			2			V
Bias current			4.6			mA
Short-circuit output current	$V_I = 35\text{ V}$		250			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 17\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		μA78M10Y			UNIT
			MIN	TYP	MAX	
Output voltage‡			10			V
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 12.5\text{ V to }28\text{ V}$	7			mV
		$V_I = 14\text{ V to }28\text{ V}$	2			
Ripple rejection	$V_I = 15\text{ V to }25\text{ V}$,	$I_O = 300\text{ mA}$, $f = 120\text{ Hz}$	80			dB
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		25			mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10			
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$		-1			mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		64			μV
Dropout voltage			2			V
Bias current			4.7			mA
Short-circuit output current	$V_I = 35\text{ V}$		245			mA
Peak output current			0.7			A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



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electrical characteristics at specified virtual junction temperature, $V_I = 19\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	μA78M12Y			UNIT
		MIN	TYP	MAX	
Output voltage‡			12		V
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 14.5\text{ V to }30\text{ V}$	8		mV
		$V_I = 16\text{ V to }30\text{ V}$	2		
Ripple rejection	$V_I = 15\text{ V to }25\text{ V}$, $I_O = 300\text{ mA}$, $f = 120\text{ Hz}$		80		dB
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		25		mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10		
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$		-1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		75		μV
Dropout voltage			2		V
Bias current			4.8		mA
Short-circuit output current	$V_I = 35\text{ V}$		240		mA
Peak output current			0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 23\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	μA78M15C			UNIT
		MIN	TYP	MAX	
Output voltage‡			15		V
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 17.5\text{ V to }30\text{ V}$	10		mV
		$V_I = 20\text{ V to }30\text{ V}$	3		
Ripple rejection	$V_I = 18.5\text{ V to }28.5\text{ V}$, $I_O = 300\text{ mA}$, $f = 120\text{ Hz}$		70		dB
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		25		mV
	$I_O = 5\text{ mA to }200\text{ mA}$		10		
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$		-1		mV/°C
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		90		μV
Dropout voltage			2		V
Bias current			4.8		mA
Short-circuit output current	$V_I = 35\text{ V}$		240		mA
Peak output current			0.7		A

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

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electrical characteristics at specified virtual junction temperature, $V_I = 29\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		μA78M20C			UNIT	
			MIN	TYP	MAX		
Output voltage‡			20			V	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 23\text{ V to }35\text{ V}$	10			mV	
		$V_I = 24\text{ V to }35\text{ V}$	5				
Ripple rejection	$V_I = 24\text{ V to }34\text{ V}$,	$f = 120\text{ Hz}$,	$I_O = 300\text{ mA}$	70			dB
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		30			mV	
	$I_O = 5\text{ mA to }200\text{ mA}$		10				
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$		-1.1			mV/°C	
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		110			μV	
Dropout voltage			2			V	
Bias current			4.9			mA	
Short-circuit output current	$V_I = 35\text{ V}$		240			mA	
Peak output current			0.7			A	

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 33\text{ V}$, $I_O = 350\text{ mA}$, $T_J = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		μA78M24Y			UNIT	
			MIN	TYP	MAX		
Output voltage‡			24			V	
Input voltage regulation	$I_O = 200\text{ mA}$	$V_I = 27\text{ V to }38\text{ V}$	10			mV	
		$V_I = 28\text{ V to }38\text{ V}$	5				
Ripple rejection	$V_I = 28\text{ V to }38\text{ V}$,	$I_O = 300\text{ mA}$,	$f = 120\text{ Hz}$	70			dB
Output voltage regulation	$I_O = 5\text{ mA to }500\text{ mA}$		30			mV	
	$I_O = 5\text{ mA to }200\text{ mA}$		10				
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$		-1.2			mV/°C	
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$		170			μV	
Dropout voltage			2			V	
Bias current			5			mA	
Short-circuit output current	$V_I = 35\text{ V}$		240			mA	
Peak output current			0.7			A	

† All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



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